NSN 5961-00-510-3953

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-510-3953 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches Overall Diameter: Between 0.335 inches and 0.370 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 2.50 amperes forward current, total rms nanoamperes and 100.00 amperes peak forward surge current nanoamperes **Power Rating Per Characteristic:** 16.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius ambient air **Special Features:** Third terminal may be omitted **Test Data Document:** 70210-944147 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: